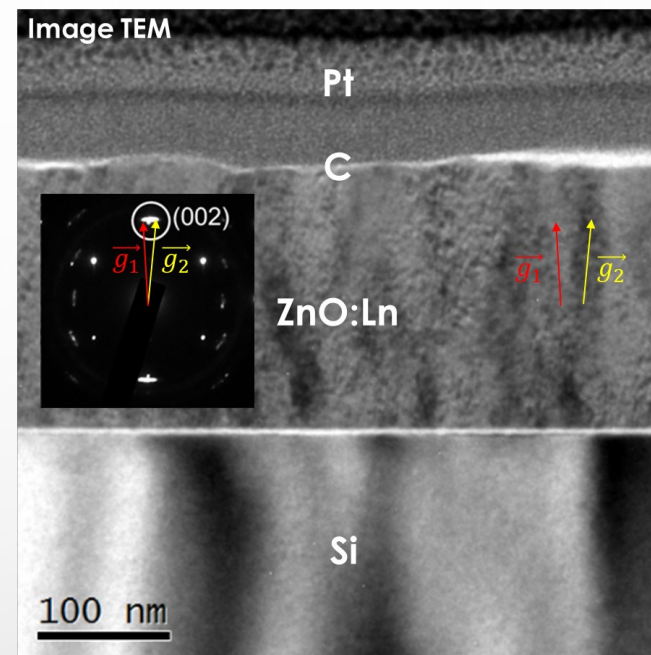




## Structural Evolution in Annealed (Eu,Tb) Doped ZnO/Si Nanoscale Junction

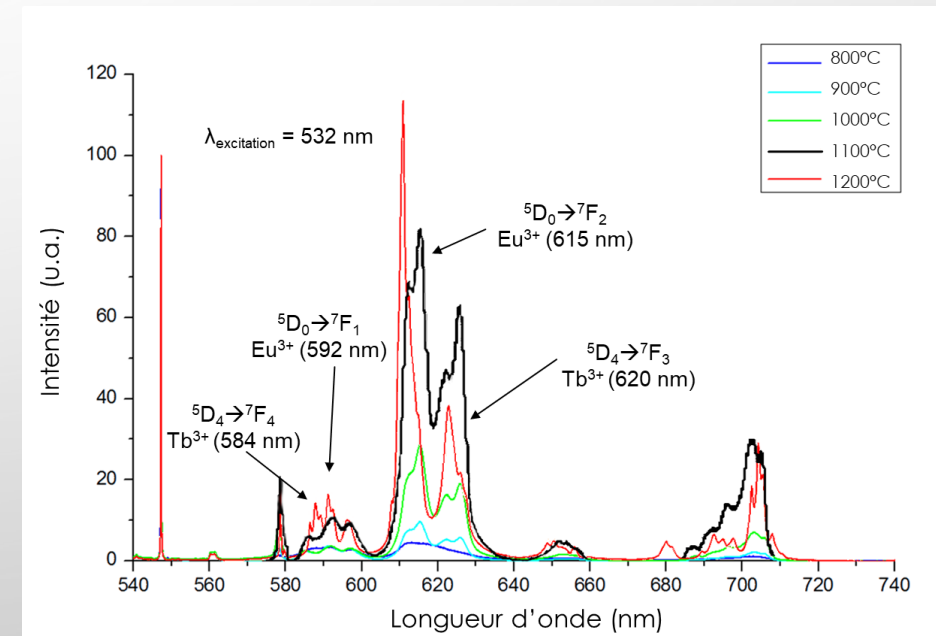
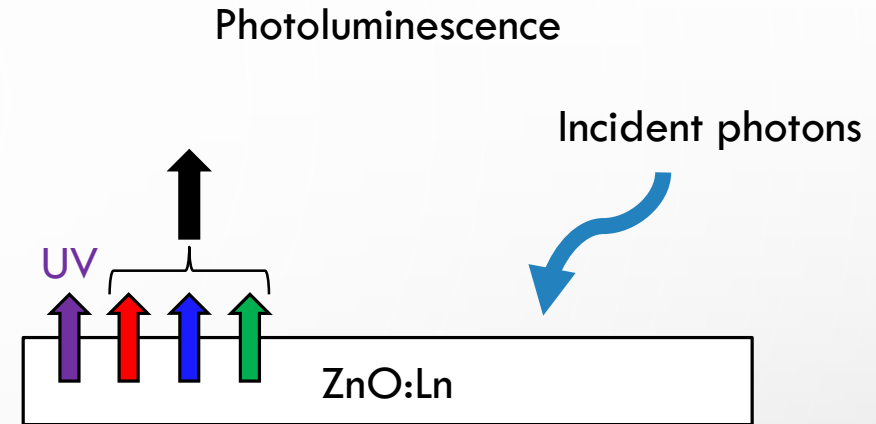
*DENIS PELLOQUIN*

CRISMAT, UMR CNRS 6508, ENSICAEN, Normandie Université,  
6 Boulevard du Maréchal Juin, 14050 Caen Cedex 04, France

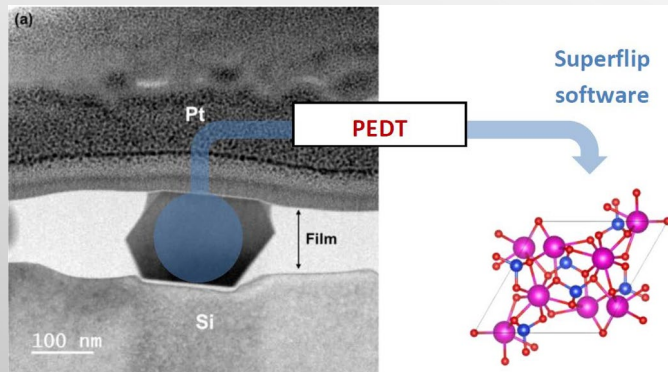


# MOTIVATIONS

- Ln doped ZnO /Si junction induces photoluminescence properties in visible spectra.
- Ln codoping and thermal annealings are efficient to improve the photoluminescence properties (selection of emitted color - best light intensity)



## Structural studies of annealed Ln doped ZnO /Si junction Case of Eu/Tb codoping



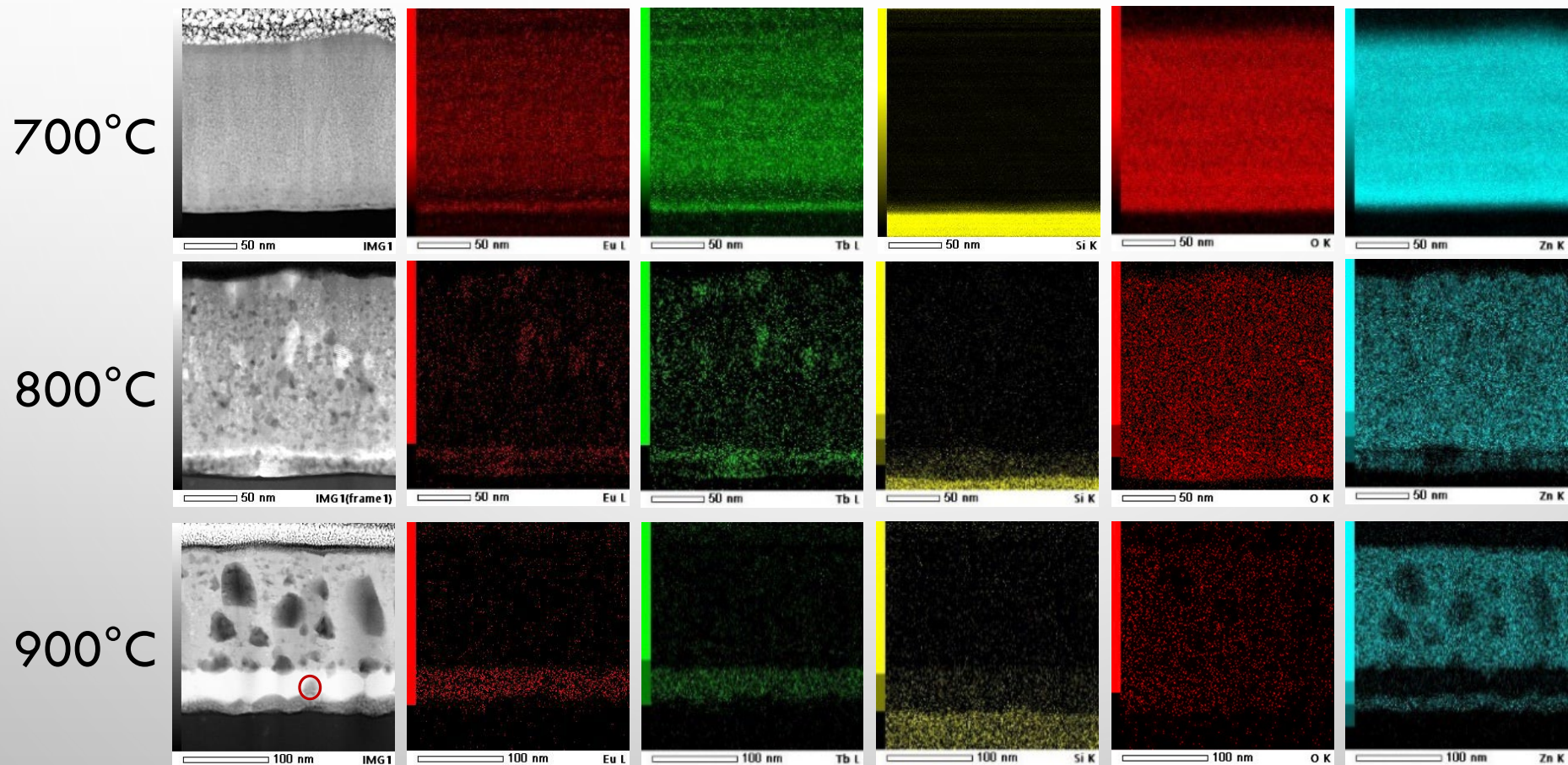
Nanometric objet

To avoid the quenching effect that limits the 4f-4f radiation (leading to the emission in the visible spectra), a low Ln doping is applied.

# EUROPIUM/TERBIUM CODOPING

Nominal codoping Eu 1.2 % and Tb 1.6 %

EDS mapping the versus annealing temperature



**From 800°C :**

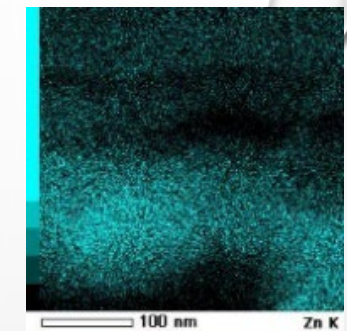
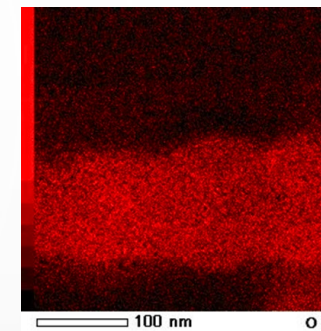
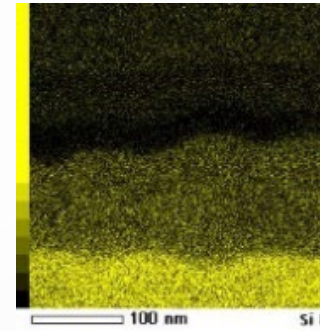
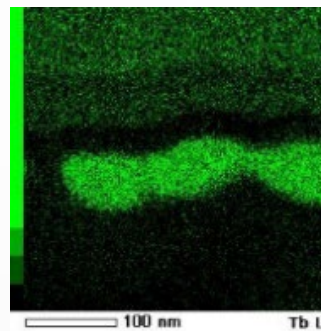
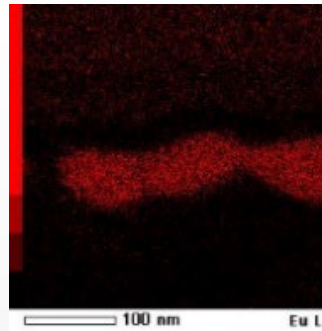
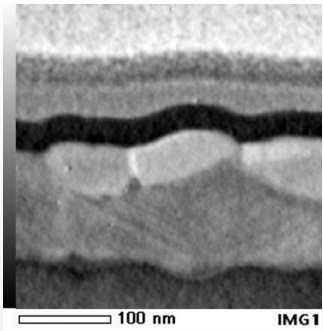
- Si species begin to migrate inside ZnO matrix
- Ln species move towards the Si interface
- Zn species crystallise with Si to form Zn<sub>2</sub>SiO<sub>4</sub> willemite structure

STEM-HAADF

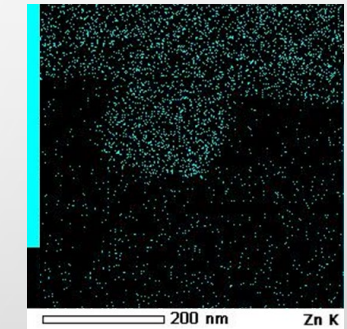
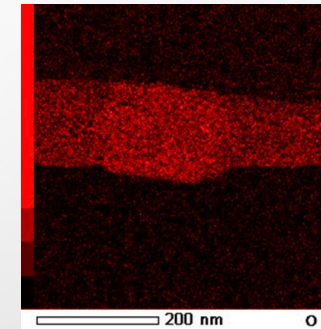
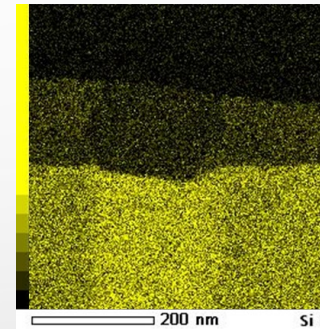
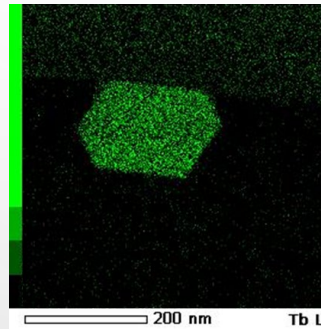
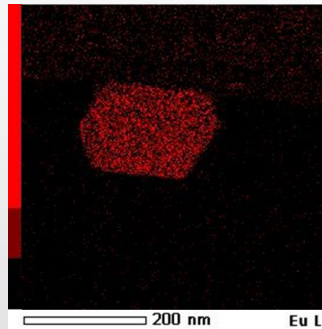
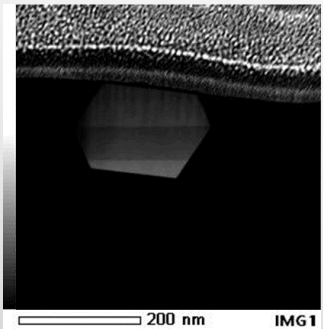
C.Guillaume, C.Leroux et al.  
Applied Surface Science, Volume 556, 2021

# EUROPIUM/TERBIUM CODOPING

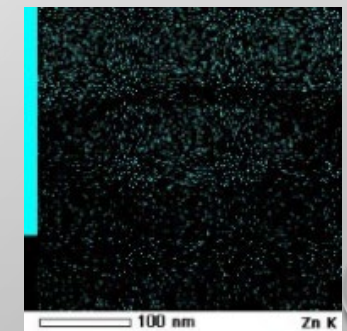
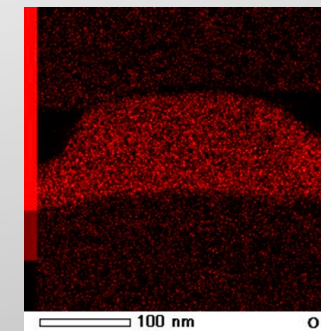
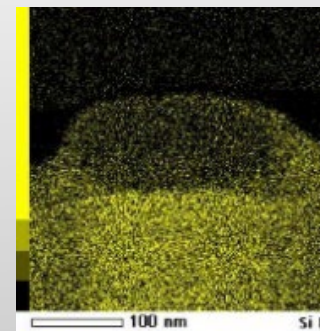
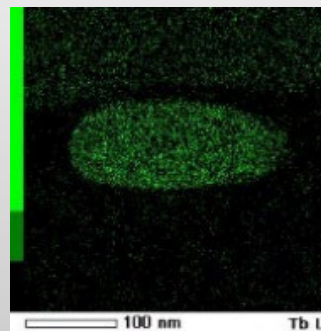
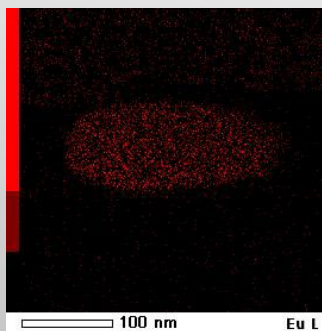
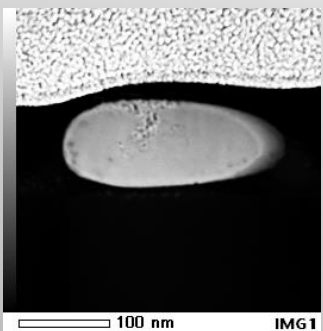
1000°C



1100°C



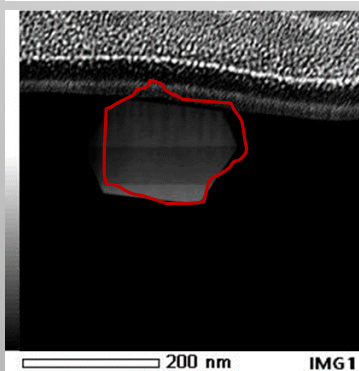
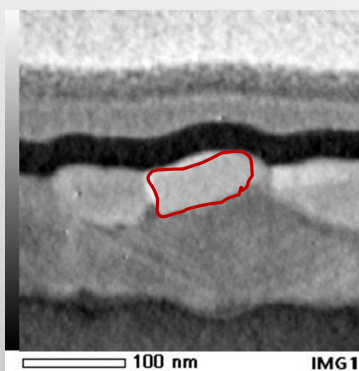
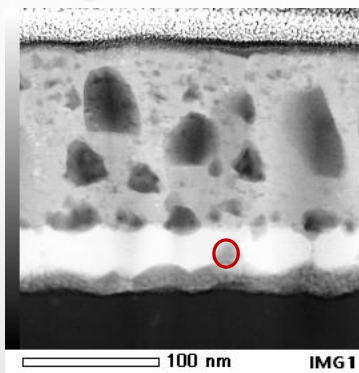
1200°C



C.Guillaume, C.Leroux et al.  
Applied Surface Science, Volume 556, 2021

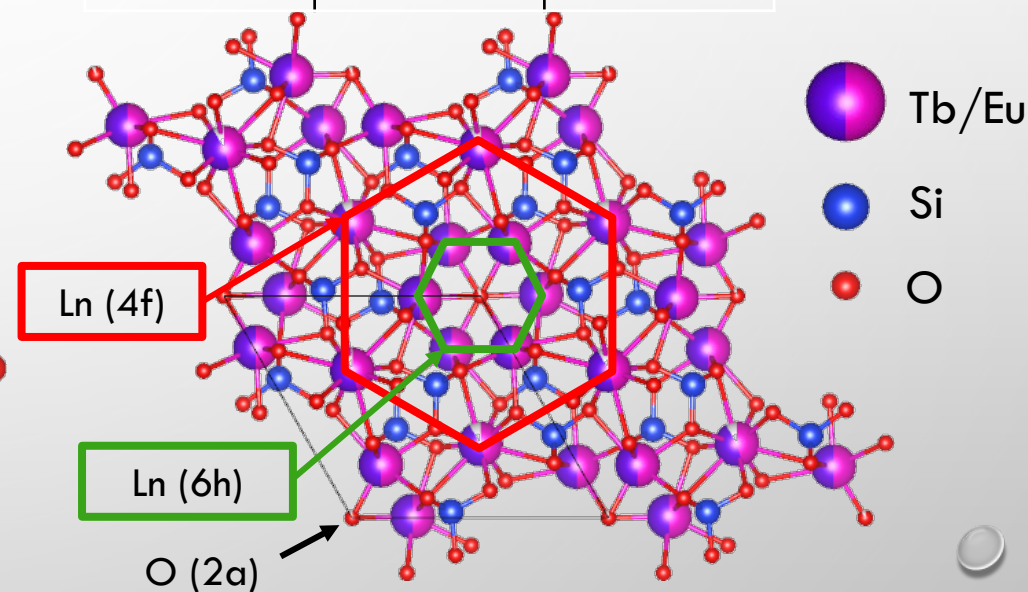
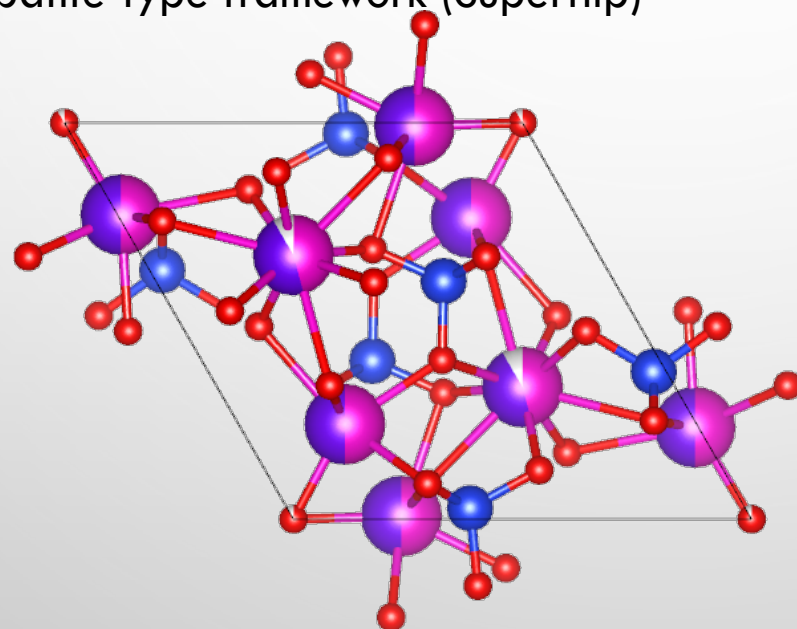
# EUROPIUM/TERBIUM CODOPING

De 900 à 1100°C :



- Common EDS results with a Ln/Si ratio close to 1.5
- PED tomography data set :  
Space group:  $P6_3/m$   
apatite-type framework (Superflip)

a (Å)	b (Å)	c (Å)
9.276(3)	9.276(3)	6.758(1)
$\alpha$ (°)	$\beta$ (°)	$\gamma$ (°)
90	90	120



Dynamicals refinements :

- Occupation site 4f  $\approx$  80 %  $\rightarrow$   $(\text{Eu,Tb})_{9,33}(\text{SiO}_4)_6\text{O}_x$

C.Leroux et al.  
*Inorg. Chem.* 2021, 60, 7, 4508–4516

# Codoping Europium/Terbium

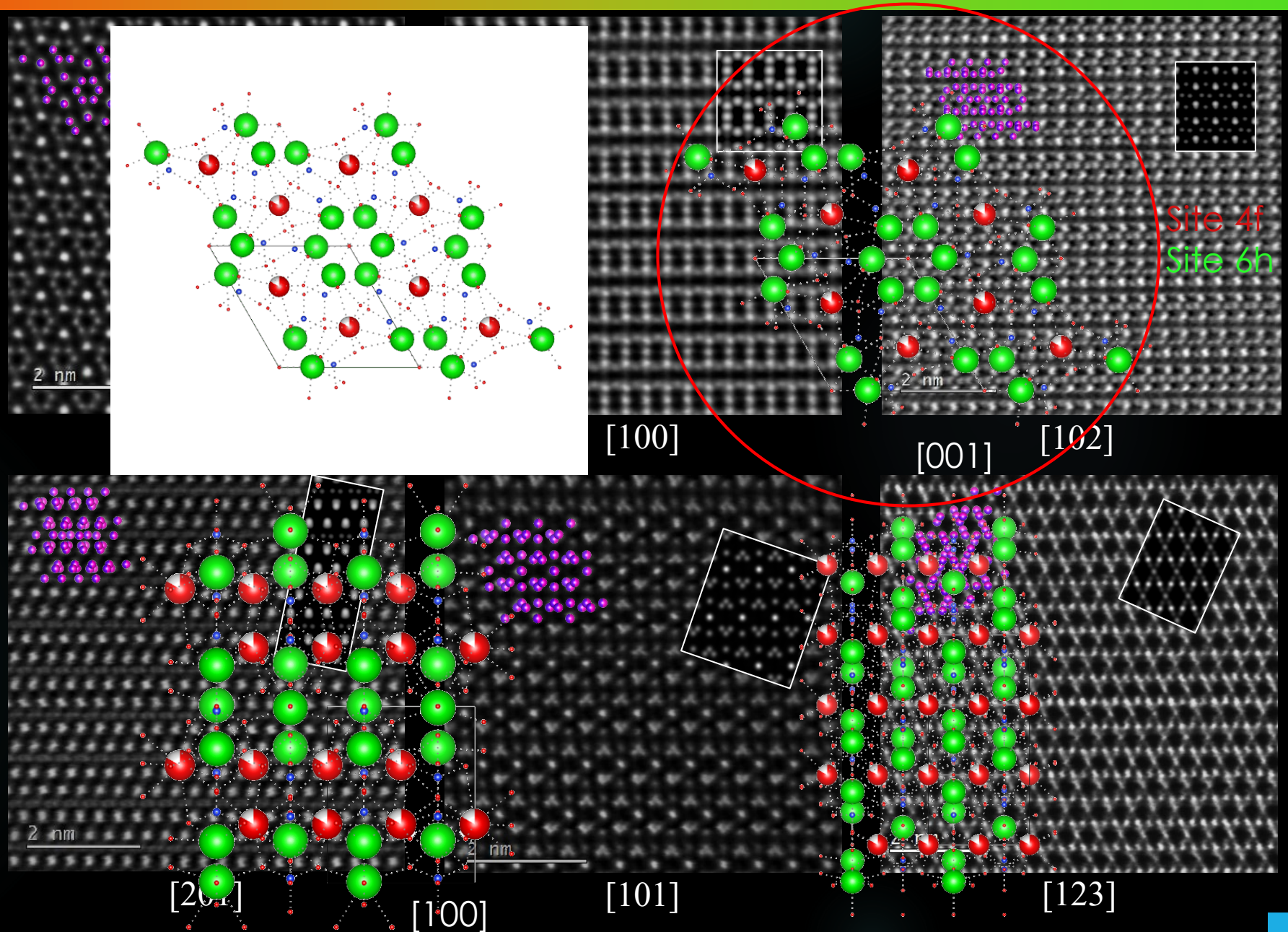
From 900 to 1000°C :

➤ Calculated images fit well the experimental ones

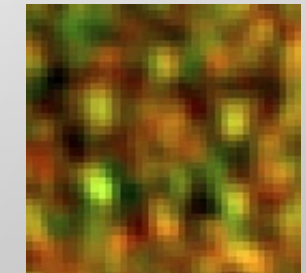
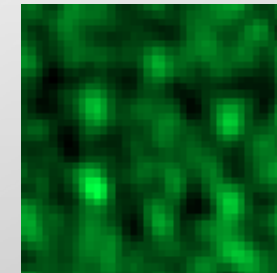
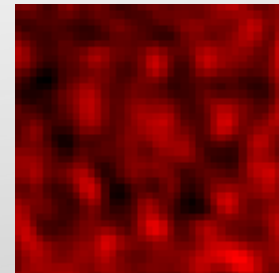
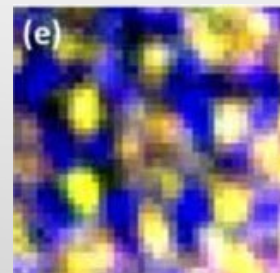
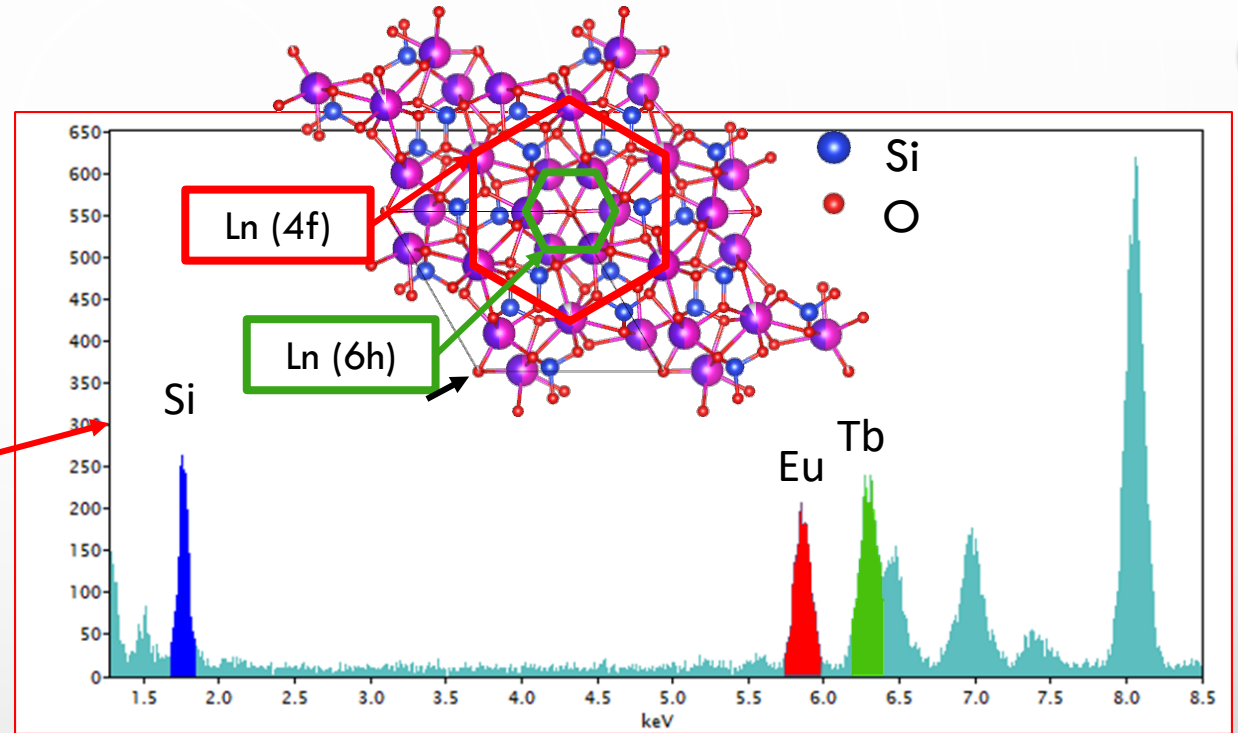
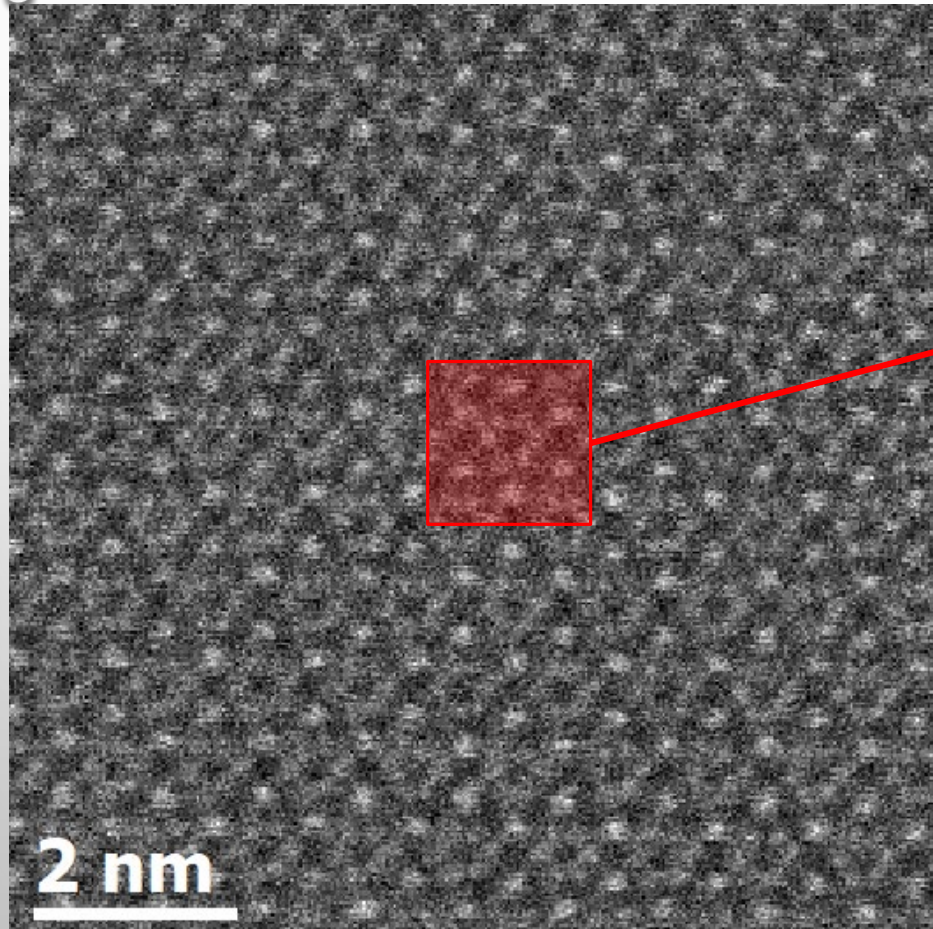
- ➔ Ordered or random Tb/Eu distribution ?
- ➔ State valence of Eu species ?

EDX et EELS spectroscopy at atomic scale on specific zone axes :

[001] or [100] or [210]



# EUROPIUM/TERBIUM CODOPING



Eu

Tb

Eu + Tb

STEM-EDX : preferential occupation 6h site by Eu and 4f site by Tb

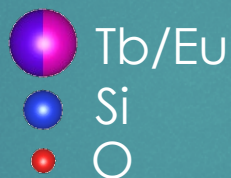
C.Leroux et al.  
*Inorg. Chem.* 2021, 60, 7, 4508–4516

# EUROPIUM/TERBIUM CODOPING

At 1200°C :

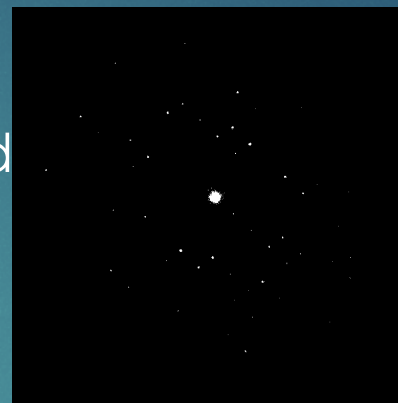
- EDS results : Ln/Si and Tb/Eu ratios lead to 1 and 1.2 respectively
- New structure : triclinic  $P\bar{1}$

a (Å)	b (Å)	c (Å)
5.33(1)	8.33(1)	2,75(1)
$\alpha$ (°)	$\beta$ (°)	$\gamma$ (°)
90.09(3)	91.95(4)	93,07(3)

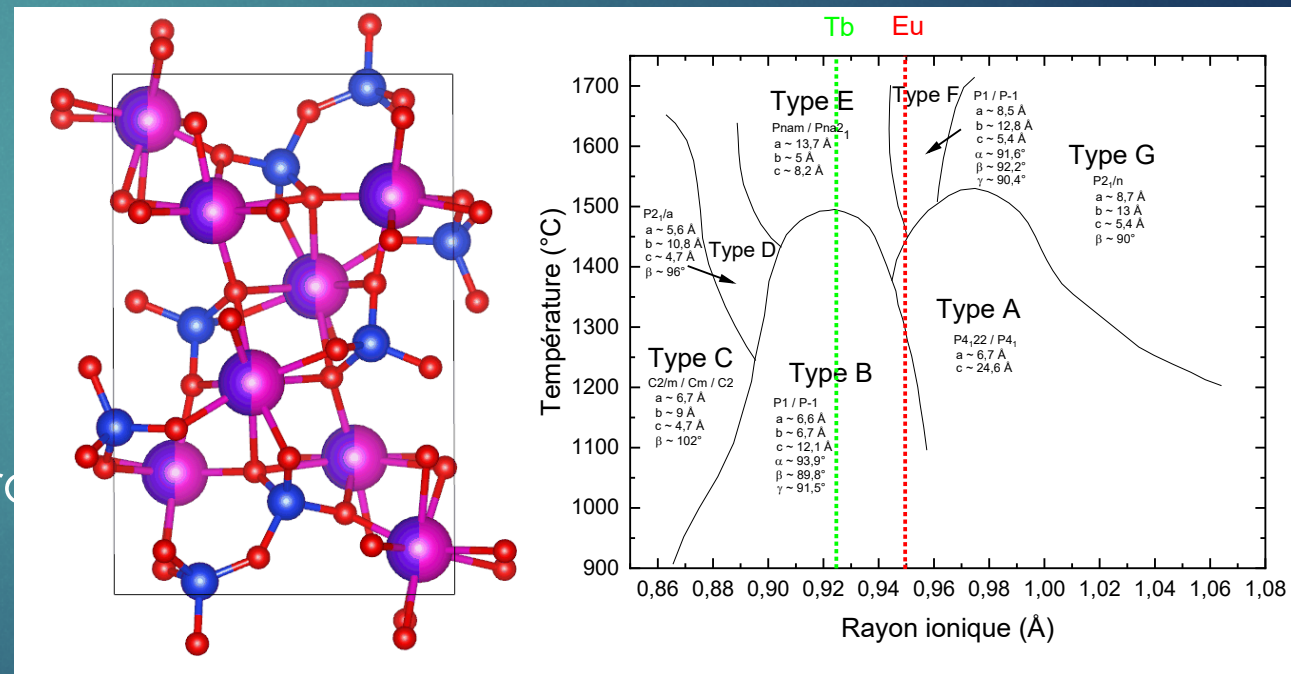
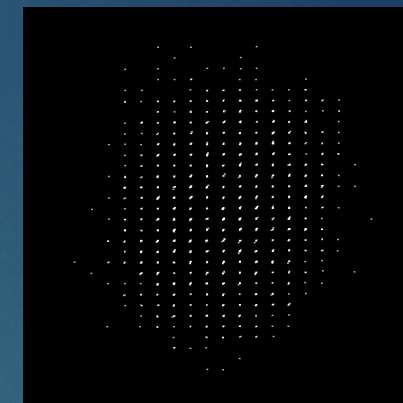


- 4 independant sites for the lanthanides
- Chemical formula:  $(Eu,Tb)_2Si_2O_7$
- type F disilicate from Felsche's nomenclature
- No deficient atomic sites

Diffraction



Réseau réciproque 3D



C.Leroux et al.

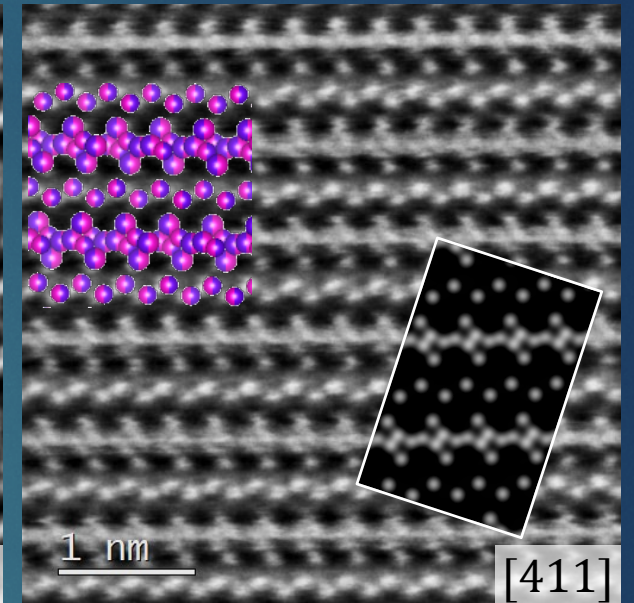
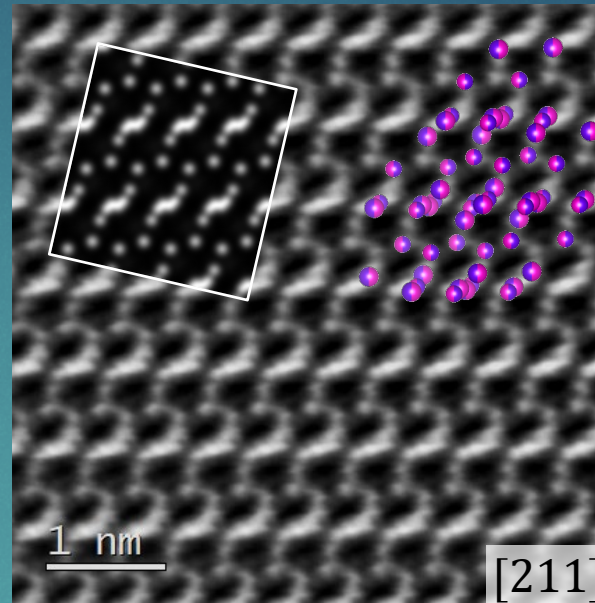
ACS Appl. Nano Mater. 2022, 5, 12, 18545-18552



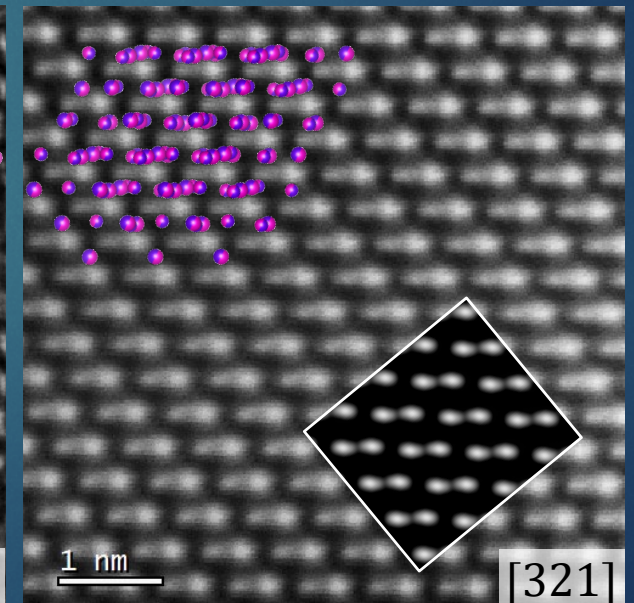
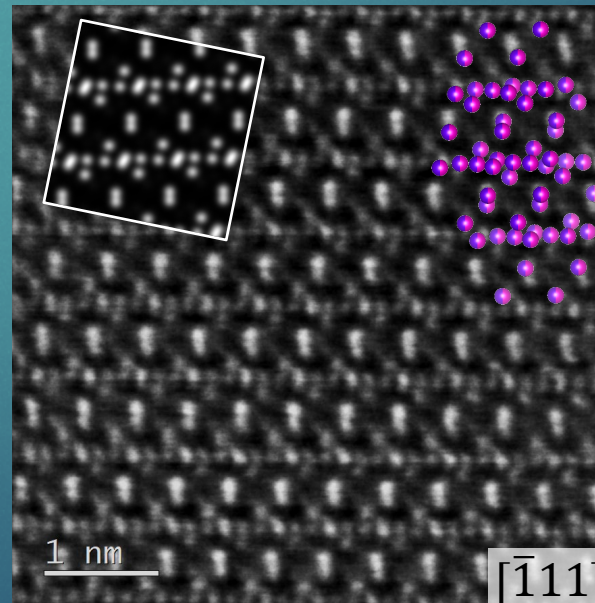
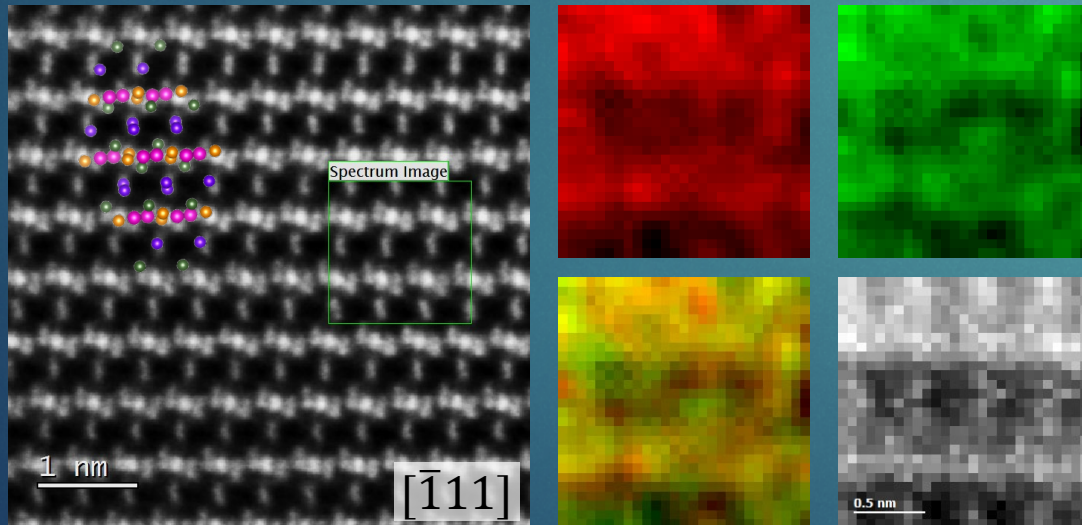
# EUROPIUM/TERBIUM CODOPING

At 1200°C :

- Calculated images fit well the experimental ones
- ➔ **No preferential Eu or Tb occupation sites ?**  
**Difficult to find zone axes leading to the projection of single Ln rows**



STEM-EDX

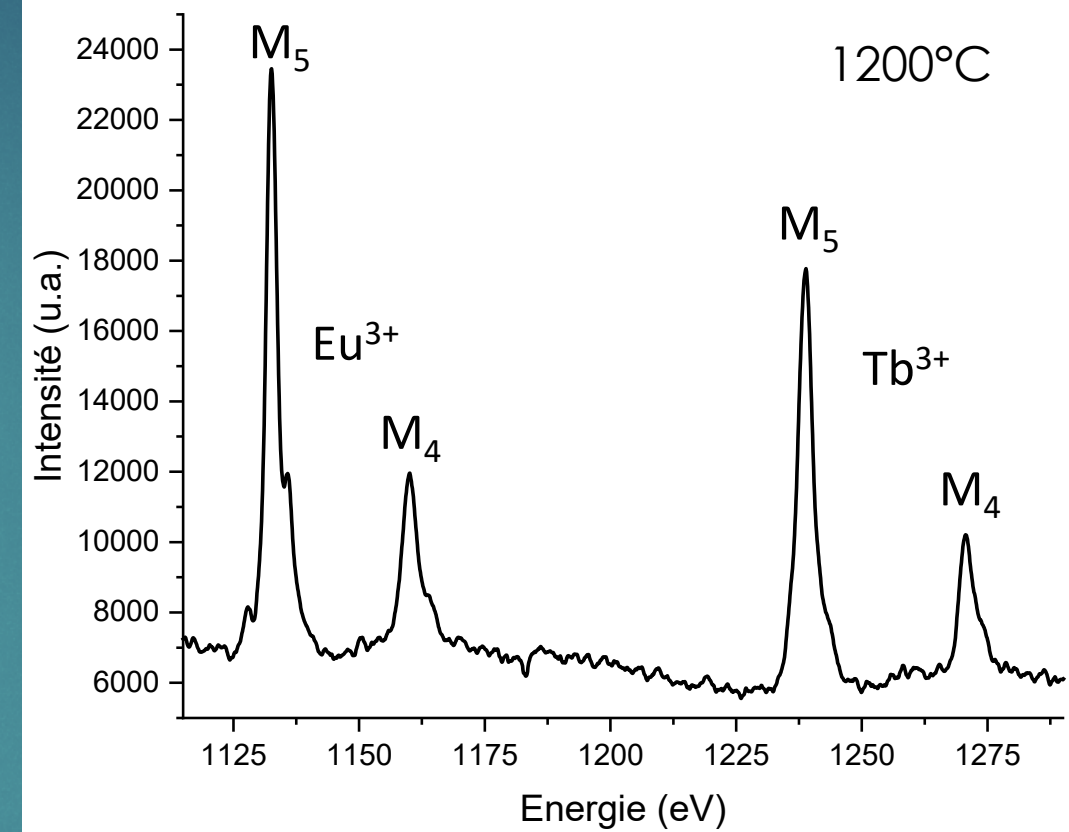
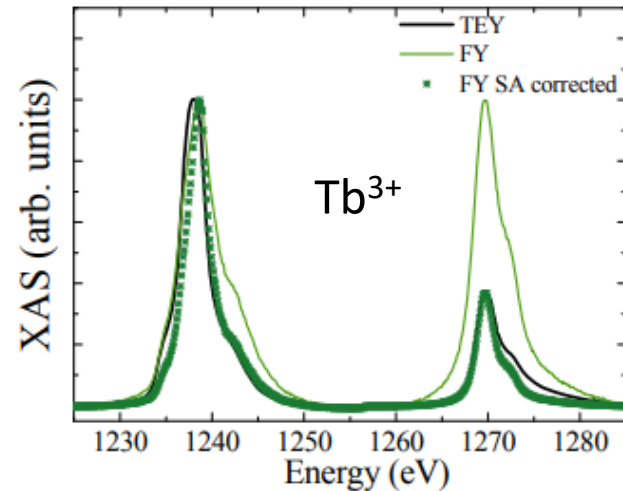
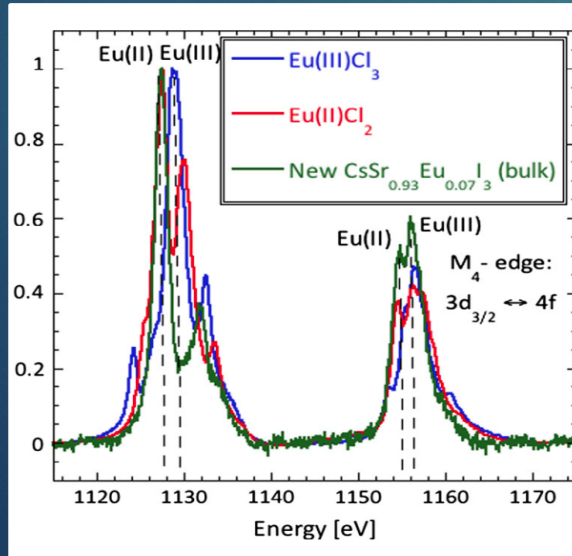


## EELS analyses

- Whatever the annealing temperature and the probed structures similar M (Ln) edges are observed on the spectra :

➔  $M_5$  Eu edge can be deconvoluted in 3 components with a main component at 1130 eV : Eu 3+

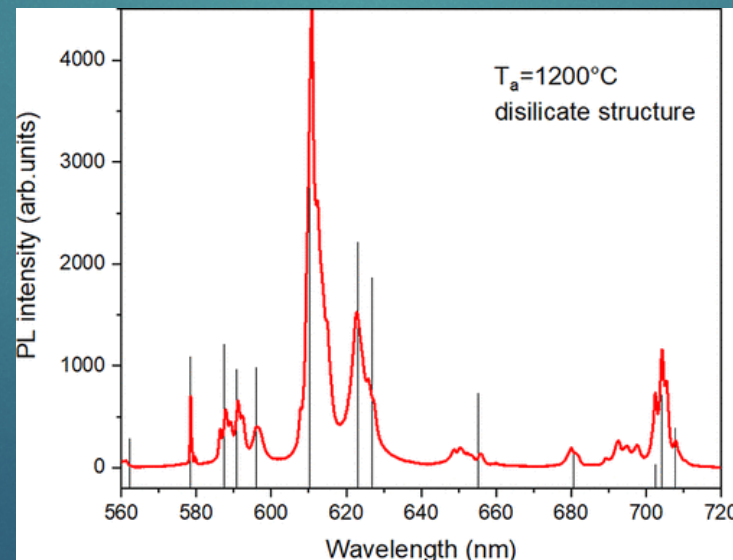
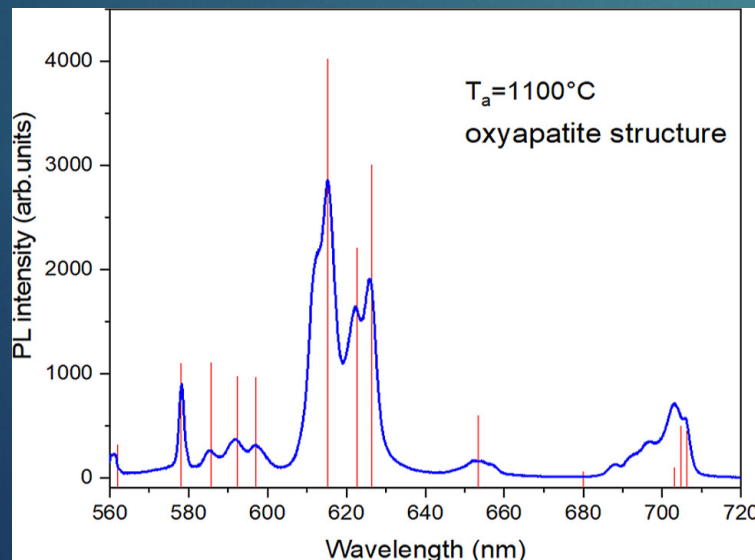
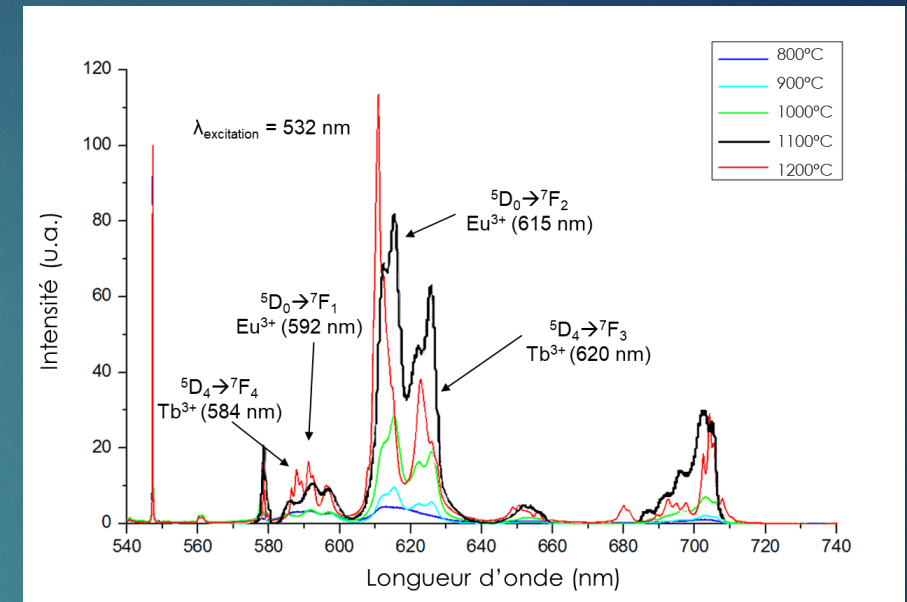
➔ Characteristic shoulders on  $M_4$  and  $M_5$  Tb edges : Tb 3+



## PL simulations from structural models :

(collaboration with the *Institute of Semiconductor Physics of the NAS – Kiev / Ukraine*)

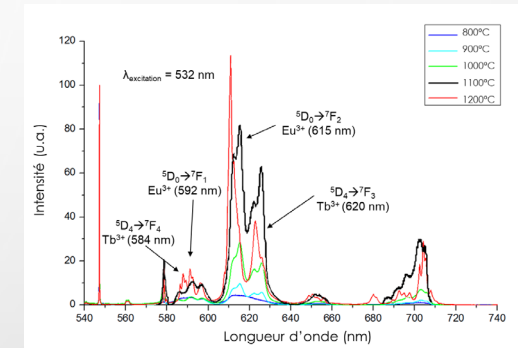
- Fit well the experimental PL spectra
- Taking into account the intensity and the width of peaks, the best PL properties are observed in disilicate  $(\text{Eu,Tb})_2\text{Si}_2\text{O}_7$  structure



*C. Leroux et al.*  
*ACS Appl. Nano Mater.* 2022, 5, 12, 18545-18552

## Concluding remarks

Annealing temperature	Structure	<6h-6h>	<6h-4f>	<4f-4f>	<Si-O>
900°C	Oxyapatite (Eu,Tb) <sub>9,33</sub> (SiO <sub>4</sub> ) <sub>6</sub> O <sub>x</sub>	3.99 Å	4.05 Å	3.40 Å	1.62 Å
1000°C		3.96 Å	4.02 Å	3.38 Å	1.61 Å
1100°C		4.04 Å	4.08 Å	3.48 Å	1.63 Å
		RE-RE ranging from 3.4 to 4.04 Å			
1200°C	F- Disilicate (Eu,Tb) <sub>2</sub> Si <sub>2</sub> O <sub>7</sub>	<RE-RE>			1.60 Å
		4.02 Å (ranging from 3.68 to 4.47 Å)			1.60 Å



The non-stoichiometric oxyapatite structure is an intermediate phase before the final disilicate formation : the gradually increasing of the average size of nanometric inclusions (from 170nm at 1100°C up to 225nm at 1200°C) bases this interpretation

The distances between RE elements in disilicate compound are more favorable to the observed energy transfer from Tb<sup>3+</sup> to Eu<sup>3+</sup>

# ACKNOWLEDGEMENTS

## Thanks to

- **Dr Chris Leroux and Philippe Boullay (CRISMAT-Caen)**
- **Pr Xavier Portier and Dr Clement Guillaume (CIMAP/CRISMAT-Caen)**
- **Dr Z. Zhuchenko and A. Zolotovskiy (Institute of Semiconductor Physics-Kiev)**